

Cite this: *RSC Adv.*, 2018, 8, 39421

Rationalization of hydrogen production by bulk g-C₃N₄: an in-depth correlation between physico-chemical parameters and solar light photocatalysis†

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The aim of this work is the systematic study of the photocatalytic activity of bulk graphitic carbon nitride (g-C₃N₄) in relation with the physical–chemical, structural and optical properties of the semiconductor. Fourteen g-C₃N₄ samples have been prepared by thermal condensation starting from three different precursor (melamine, dicyandiamide and urea) and exploring various temperatures (in the range 500–700 °C). The materials obtained have been deeply characterized by high resolution scanning electron microscopy, thermogravimetric analysis, X-ray diffraction, nitrogen adsorption measurements (BET method), X-ray photoelectron spectroscopy and diffuse reflectance spectroscopy. Each semiconductor, coupled with Pt co-catalyst, was tested for hydrogen gas production from aqueous triethanolamine as model sacrificial agent, under simulated solar light. The hydrogen evolution profiles turned out to be strictly dependent on precursor type and synthesis temperature, with the highest evolution rate observed for the samples series produced from urea (up to ca. 4400 μmol g⁻¹ h⁻¹). The results, corroborated by the excellent inter-day precision of irradiation tests (RSD < 5%, *n* = 3) together with the good batch-to-batch reproducibility (RSD < 11%, *n* = 3), were critically discussed. Apart from the appealing production values obtained using the as-prepared materials, it was importantly pointed out that, besides crystallinity and visible light absorption, the photocatalytic behavior is definitely correlated to the surface area, which is dependent on the synthesis conditions, that is polymerization temperature and nature of g-C₃N₄ precursor. Overall, this systematic investigation demonstrated that, contrary to the polymerization degree (sp²/sp³ carbon ratio), surface area is the real determinant parameter for g-C₃N₄ hydrogen evolution activity.

Received 26th October 2018
Accepted 17th November 2018

DOI: 10.1039/c8ra08880b

rsc.li/rsc-advances

1. Introduction

Graphitic carbon nitride, known as g-C₃N₄, is nowadays considered the most appealing visible-light photocatalyst for a variety of applications ranging from hydrogen evolution, overall water splitting, organic pollutants degradation, to CO₂ photoreduction. More recently, this material has been proposed also for biomedical applications, and analytical sample

preparation and sensing.^{1–5} All these possibilities are due to the peculiar electronic structure of g-C₃N₄, the relatively narrow band gap (ca. 2.7 eV) and conduction and valence band positions suitable to run relevant oxidation and reduction processes.⁶ In addition, g-C₃N₄ is stable at high temperatures (up to 600 °C in air), it can be easily prepared starting from cheap precursors, it is stable in several organic solvents, and it has a high chemical stability in both acidic and alkaline environments.^{1–4} Usually, g-C₃N₄ is prepared by a simple thermal condensation of a nitrogen-rich precursor such as cyanamide,⁷ dicyandiamide (DCD),⁸ melamine (MLM),⁹ thiourea,¹⁰ or urea,¹¹ which provide graphitic-like layered structures consisting of 2D sheets composed of tris-*s*-triazines interconnected *via* tertiary amines.

Most of the studies available in the literature dealing with g-C₃N₄ are focused on the photocatalytic hydrogen evolution underlining that g-C₃N₄ is a viable alternative to the known materials for hydrogen production under visible-light

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† Electronic supplementary information (ESI) available. See DOI: 10.1039/c8ra08880b



irradiation.^{1–4} The photocatalytic activity of as-prepared g-C₃N₄ is considered of relatively low-efficiency and several new synthetic strategies have been recently proposed to improve the H₂ production. Among these, for pure g-C₃N₄ we found supra-molecular pre-assembly, molten salt, ionic liquid, preparation of 2D nanosheets, and several modifications of carbon nitride by heteroatomic doping, creation of hybrid structures, heteromolecular doping, co-catalysis² and thermal oxidation.¹² In addition, other strategies are focused on the preparation of semiconductor–semiconductor heterojunctions as a way to enhance the photocatalytic performance by promoting the separation of photoinduced carriers. In this context, many semiconductors have been coupled with g-C₃N₄ to form such junctions.¹

Focusing on the photocatalytic hydrogen evolution promoted by g-C₃N₄, it can be observed that, despite a very intensive investigation carried out in the last years, very conflicting results are reported in the current literature. Even in the case of the same g-C₃N₄ precursor and reaction temperature, significant differences in the photocatalytic hydrogen production were observed.^{10,13–16} As a matter of fact, the experimental conditions during the precursor condensation may affect the final characteristics of g-C₃N₄ in terms of crystal structure, degree of polymerization, protonation *etc.* These features, in turn, influence the photocatalytic hydrogen production efficiency. For example, a recent investigation on g-C₃N₄ prepared by urea, DCD or thiourea, put in prominence the relevant role of protonation and degree of polymerization as key parameters in the preparation of highly efficient g-C₃N₄.¹⁷ In particular, the increase in proton concentration was identified as a fundamental parameter,¹⁷ even more important than surface area. On the same line, other authors focused on the chemical composition and structure of g-C₃N₄ prepared by cyanuric acid and MLM and highlighted the key role of chemical composition in terms of *s*-triazine or tri-*s*-triazine units in the photocatalytic performance.¹⁸ Another relevant parameter affecting the catalytic ability of g-C₃N₄ has been identified in the defects that can be present in the final product, which may limit the electron–hole separation and transport.^{19–21} Other key features concern with the morphology of the final g-C₃N₄ prepared, in particular with reference to the layered structure. It has been pointed out that if layered g-C₃N₄ is prepared into mono- or few-layer g-C₃N₄ sheets, the photocatalytic performance is greatly improved.^{20,22–26} However, most methods to achieve mono- or few-layers g-C₃N₄ require relatively complex post-synthesis treatments and may result in very low amounts of g-C₃N₄ nanosheets.²⁰ Finally, very promising results in terms of photoactivity have been recently obtained through the use of molten salts to accelerate the polymerization process and further tailor the properties of carbon nitride polymers.^{27–29} Materials prepared in this way have a rich variety of structural features that can be modulated through the use of different alkaline halides.²⁷

Overall, notwithstanding the rich literature appeared on g-C₃N₄ in the last years, there is still a significant spread in the correlation of the reported photocatalytic behavior with synthetic procedure and physico-chemical properties. In order

to try to shed some light on this issue, in the present paper we are reporting a systematic and extensive investigation on bulk g-C₃N₄ prepared by thermal condensation of three different precursors, *i.e.* urea, DCD, and MLM, at different temperatures (500, 550, 600, 650 and 700 °C). All syntheses were carried out under the same and reproducible conditions in order to be able to compare the characterization results among the different samples series. All samples have been characterized by means of X-ray diffraction (XRD), X-ray photoelectron spectroscopy (XPS), nitrogen adsorption measurements at –196.15 °C (BET method), scanning electron microscopy (SEM), thermogravimetric analysis (TGA), and then they were tested for hydrogen photoproduction under simulated solar light.

We highlight that in this work we intentionally selected a very simple synthetic method and the most common precursors in order to show that high photocatalytic activities can be obtained with no need for complex post-synthesis treatment and co-dopings. This is an essential result to make g-C₃N₄ a real large-scale photocatalyst for several applicative purposes where the ease of synthesis and the time and cost savings represent key factors. Most importantly, through the extensive physico-chemical characterization of a large number of samples, we were able to highlight which are the most relevant parameters affecting the properties of g-C₃N₄ and to provide a correlation of hydrogen production with morphology, crystal structure and optical features.

2. Experimental

2.1. Preparation of g-C₃N₄

The g-C₃N₄ samples have been synthesized by polymerization of DCD (NH₂C(=NH)NHCN, Aldrich, 99%), urea (CH₄N₂O, Aldrich > 99.5%), and MLM (C₃H₆N₆, Aldrich 99%) by the following thermal treatment (under N₂ flow): heating (10 °C min^{–1}) to the selected temperature (500, 550, 600, 650 or 700 °C), isothermal step for 4 h followed by cooling to room temperature (1 °C min^{–1}). Syntheses have been carried out in a partially closed alumina crucible.

2.2. Characterization of the g-C₃N₄ samples

The crystal structure of each sample has been characterized by room temperature Cu-radiation XRD acquired with a Bruker D8 diffractometer in the 5–35° angular range (5 s per step, step size 0.02°). Microstructural characterization was made using a high-resolution scanning electron microscope (SEM, TES-CAN Mira 3) operated at 15 kV.

Nitrogen adsorption isotherms at –196.15 °C were acquired for each sample by using a Quantachrome Nova 2200e volumetric device. Preliminarily to the analysis, samples were out-gassed at 250 °C for 3 h. The specific surface areas were obtained by applying the BET method to the collected data.

XPS measurements have been collected through a properly calibrated VG-Scienta R3000 electron analyzer, with the Al *Kα* (1486.6 eV) emission line of a dual-anode, non-monochromatized PsP X-ray source.³⁰ The final overall energy resolution was about 0.9 eV. For this analysis, the samples have



been pressed into pellets and mounted with carbon tape. Due to mild electrical charge accumulation effects, the energy scale has been defined through the position of the main C 1s peak component, which corresponds in this case to the N=C-N bond. Given the relatively large pellets thickness, only the C₃N₄ photoemission signal has been probed.

Thermogravimetric analyses have been performed by heating 5–8 g of each sample from room temperature up to 1000 °C at 10 °C min⁻¹ under N₂ atmosphere in a Pt pan by using a Q5000 equipment by TA Instrument (USA).

The optical diffuse reflectance spectra of the different samples were measured from 0.8 to 4.5 eV (250–1500 nm, in steps of 1 nm) on a Varian Cary 6000i spectrophotometer equipped with an integrating sphere. For this type of measurement, polycrystalline powders were compacted into pellets of about 10 mm in diameter, and reflectance spectra were calibrated using a standard reference disk.

2.3. Photocatalytic hydrogen gas production tests

Experiments were conducted on triethanolamine (TEOA, ≥99% Sigma-Aldrich) aqueous solutions (10%, v/v) irradiated in Pyrex glass containers (28 mL capacity, 21 mL sample³¹). After addition of the catalyst (1 g L⁻¹), the suspension was deoxygenated by Ar (99.999%, Sapio S.r.l.) bubbling (20 min) to obtain anoxic conditions, and irradiated under magnetic stirring for 6 h. Pt was loaded on the catalyst surface (3 wt%) by *in situ* photo-deposition using H₂PtCl₆ (~38% Pt basis, Sigma-Aldrich).^{12,32} Transmission Electron Microscopy (TEM) inspection of Pt-loaded samples is reported in the ESI,† showing a spherical shape of Pt particles with average grain-size around 40–50 nm. Irradiation was performed under simulated solar light using a Solar Box 1500e (CO.FO.ME.GRA S.r.l., Milan, Italy) set at a power factor 500 W m⁻², and equipped with UV outdoor filter of soda lime glass IR-treated. The photon flux, determined experimentally by 2-nitrobenzaldehyde actinometry (300–410 nm),³³ was 1.53 × 10⁻⁷ moles per photons per s. Triplicate irradiation experiments were always performed. The headspace evolved gas was quantified by gas chromatography coupled with thermal conductivity detection (GC-TCD), as previously described.³⁴ All results throughout the manuscript are expressed in terms of H₂ evolution rate (HER), as μmoles of evolved gas per gram of catalyst per hour (μmoles g⁻¹ h⁻¹).

3. Results and discussion

The g-C₃N₄ samples, prepared according to the Experimental section, underwent a full characterization to provide a correlation between physico-chemical properties and photocatalytic activity.

3.1. Reaction yields

Samples from DCD and MLM precursors have been obtained at five different temperatures, *i.e.* at 500, 550, 600, 650 and 700 °C. On the other hand, only four samples (at 500, 550, 600 and 650 °C) have been obtained from the urea precursor after the thermal treatment. This is related to the different reaction

yields of the thermal condensation reaction starting from the three different precursors, which are indicated in Fig. 1.

All results presented in Fig. 1 are relative to the same batch size for all syntheses (about 5 grams of precursor) and show that the highest yields are obtained by using DCD as precursor, followed by MLM and urea. For all precursors the yield reduced by increasing temperature and, in the case of urea, which had the lowest yields at any temperature, it was not possible to obtain any product above 650 °C. As a consequence, in the remaining of the paper, the data at 700 °C for g-C₃N₄ prepared from this precursor are not available.

3.2. X-ray diffraction

Fig. 2a–c reports the XRD patterns for all g-C₃N₄ samples investigated in the present work. Temperatures in the three panels represent the reaction temperatures for the materials preparation.

The patterns reported in Fig. 2a–c show the typical appearance of g-C₃N₄ diffraction, characterized by a first peak around 12.5°, attributed to the (100) plane, due to the intra-layer *d*-spacing, and a main peak at 2θ *ca.* 27°, reported as the (002) plane, ascribed to the distance between the layers of the graphitic material. From the simple visual inspection of Fig. 2, in particular for the samples prepared starting from DCD and MLM, it is possible to observe some trends as a function of increasing reaction temperature, namely, the first peak at about 12.5° becomes progressively less intense and nearly undetectable for the sample prepared at 600 °C while the main peak at about 27° becomes sharper and shifts at higher angles. For instance, the shift of the main peak observed for the DCD-derived sample is from about 26.85° at the synthesis temperature of 500 °C to about 27.60° for the sample prepared at 700 °C.

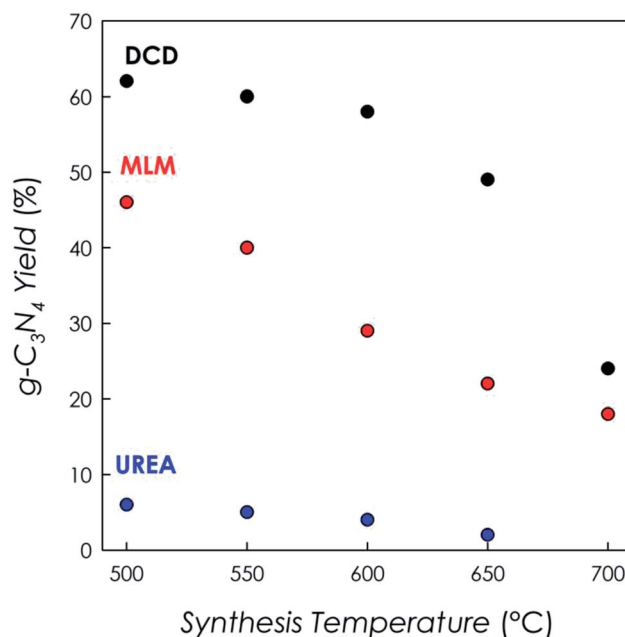


Fig. 1 Reaction yields of g-C₃N₄ for the three different precursors at the different temperatures as determined by TGA measurements.



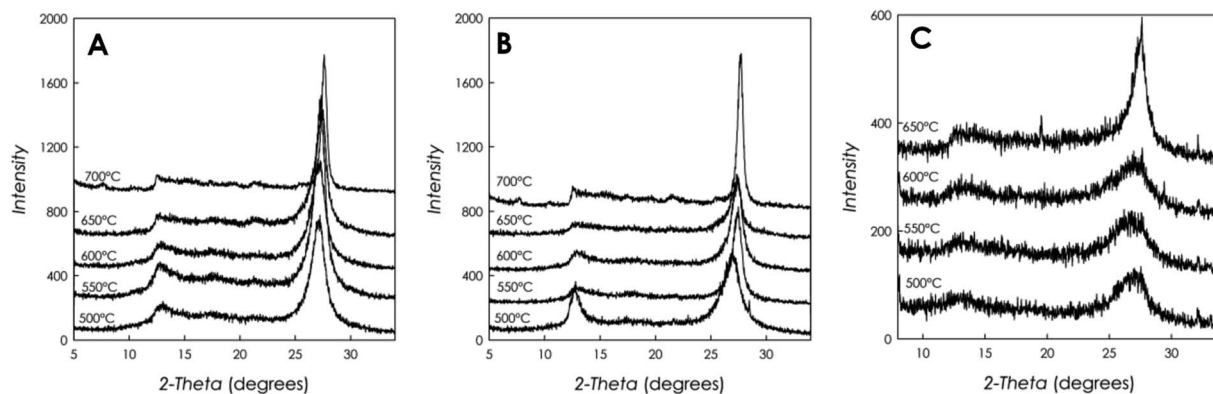


Fig. 2 XRD patterns for the $g\text{-C}_3\text{N}_4$ samples prepared starting from different precursors and at different polymerization temperatures: (a) DCD; (b) MLM; and (c) urea.

These observations suggest that the increase of condensation temperature provides a more crystalline solid phase, together with a decrease of the intra-layer spacing caused by a higher polymerization degree, which also evidences a greater disorder in the plane. At the same time, smaller inter-layer d -spacing values are observed at high temperature. The signal-to-noise ratio for the patterns in panels (a) and (b) in Fig. 2 is similar, while for the samples prepared starting from urea (panel (c)), for the same XRD acquisition parameters, such ratio is worse, suggesting a less scattering material, *i.e.*, less crystalline. In addition, the FWHM (Full Width at Half Maximum) for the $g\text{-C}_3\text{N}_4$ samples prepared from DCD and MLM are similar (*e.g.*, about 2° at 500°C) while for the samples prepared starting from urea precursor the FWHM are higher (*e.g.*, $>3^\circ$ at 500°C).

3.3. Morphology and surface area

The morphological characterization of the prepared materials was performed by SEM inspection. For the sake of brevity, in Fig. 3 we show the images acquired on the $g\text{-C}_3\text{N}_4$ samples prepared from DCD (a, b), MLM (c, d) and urea (e, f) at the lowest (left) and highest (right) synthesis temperatures. Highest synthesis temperatures are 700°C for DCD and MLM precursors and 650°C for urea (see previous discussion on reaction yields).

As it can be appreciated from the representative images selected in Fig. 3, a layered structure is evident in all samples for the powders obtained from DCD and MLM, with the size of the single layers decreasing by increasing the temperature (see the samples prepared at 700°C). In the case of urea-derived $g\text{-C}_3\text{N}_4$, the powder appears made of less extended layers already at low temperature while at high temperature the microstructure seems made of small grains compared to the above materials (the photocatalyst produced from urea is indeed the most fluffy among all samples). Essentially, by increasing the reaction temperature, a sort of “opening” of the structure occurs leaving more surface available for the catalytic reaction. These observations are in agreement with the surface area values, obtained by the BET method and reported in Table 1 for each sample as function of both synthesis temperature and precursor.

For all the samples the BET area increases with the temperature of the synthesis. Samples obtained from DCD and

MLM precursors at 500 , 550 and 600°C exhibit very low specific areas, close to the minimal detectable value of $3\text{ m}^2\text{ g}^{-1}$. This is in accordance with the SEM observations (Fig. 3a and c) that reveal a multilayered structure constituted by agglomerated sheets. For higher synthesis temperatures (650 , 700°C) the increase of the BET areas up to $36\text{ m}^2\text{ g}^{-1}$ is associated to the observed change in the samples morphology with a much-disordered structure constituted by smaller sheets (Fig. 3b and d). The samples obtained from the urea precursor at temperature of 500 – 600°C present BET areas in the range 31 – $41\text{ m}^2\text{ g}^{-1}$ while the double value of $85\text{ m}^2\text{ g}^{-1}$ is measured for samples synthesized at 650°C . These results can be attributed to the morphologies observed by SEM. The urea samples are constituted by poorly agglomerated particles and the particles size decrease for higher synthesis temperature is responsible of the increase in the surface area (Fig. 3e and f).

The surface area (around $85\text{ m}^2\text{ g}^{-1}$) observed for the urea sample prepared at the highest temperature can be considered a high value for bulk $g\text{-C}_3\text{N}_4$.³⁵ These findings can be justified considering that, during polymerization, urea (that contains oxygen) generates CO_2 and H_2O , which prevent full condensation; this hampers long-range in-plane structural packing, thus providing a material with more available surface area.³⁶

3.4. Optical properties

Fig. 4a–c report the diffuse reflectance spectra as a function of wavelength recorded for each material, as function of synthesis temperature and precursor type.

The curves clearly indicate that all materials are capable of visible-light harvesting, in fact they exhibit absorption edges above 400 nm ; for instance, the band gap of the sample synthesized from DCD (at 500°C) resulted to be $2.70(5)\text{ eV}$, in full agreement with the typical band gap of $g\text{-C}_3\text{N}_4$ semiconductors (around 2.7 eV), corresponding to an absorption edge of *ca.* 460 nm .^{6,35}

It is interesting to note that, for synthesis temperatures in the range 600 – 700°C , the profiles generally show an enhanced absorption above 400 nm and they show a less defined absorption edge due to the formation of a remarkable band almost centered at 500 nm . This behavior, observed independently of the precursor



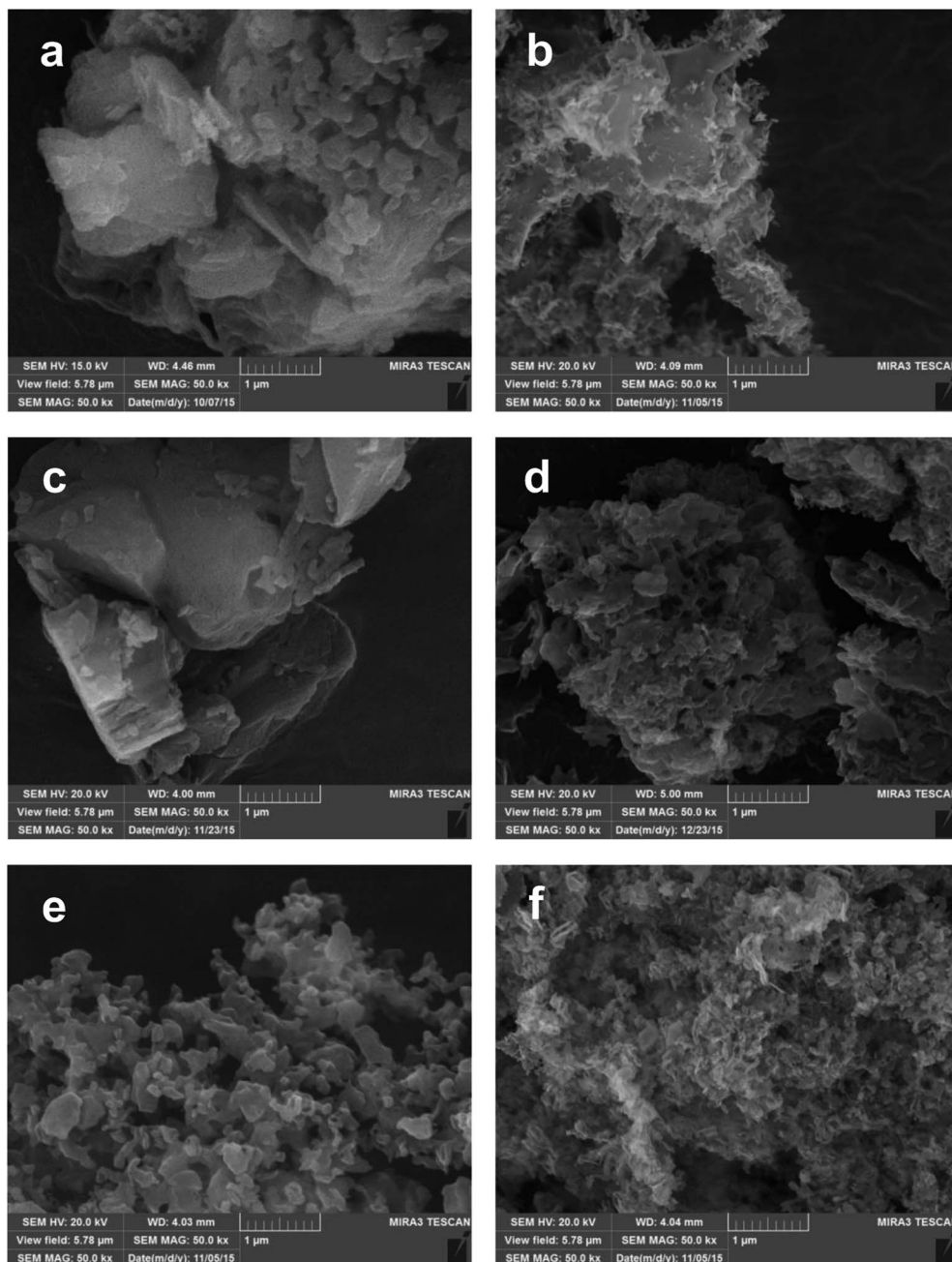


Fig. 3 SEM images collected on the g-C₃N₄ materials prepared from DCD (a, b), MLM (c, d) and urea (e, f) by thermal condensation at 500 °C (a, c, e), 700 °C (b, d) and 650 °C (f).

type, is ascribable to the typical $n-\pi^*$ transition of the asymmetric and nonplanar conjugated heptazine rings,^{12,37,38} and it suggests a greater absorption capability in the visible region for the high-temperature-polymerization samples.

3.5. XPS

The XPS analysis was carried out on the three samples prepared at lower temperatures (500 °C), as well as on the three samples prepared at the highest common temperature (650 °C). For the sample grown from urea also the sample prepared at 600 °C was considered, to confirm the trend observed in the C-C/C-N ratio with hydrogen production.

The N 1s spectra for samples with several precursors and various growth temperatures are shown in Fig. 5.

In each spectrum it is possible to discriminate the nitrogen sp² and sp³ components, consistently with the literature;¹⁷ such ratio has been evaluated through curve fitting with three Voigt peaks (an example is shown at the bottom of Fig. 5a). The main component is ascribed to C-N-C bond in the sp² configuration (BE = 399 ± 0.2 eV) while the other two peaks are usually ascribed to sp³ configuration, corresponding to N-C₃ (labelled as sp³-a in Fig. 5a, BE ≈ 400 eV) and C-N-H_x (sp³-b, BE ≈ 401.5 eV) bonds. The resulting area ratios are shown in Fig. 5b, correlated with the H₂ production yield (see later in the text).



Table 1 BET specific surface area determined for the set of g-C₃N₄ samples

Synthesis temperature (°C)	Surface area (m ² g ⁻¹) ^a		
	DCD	MLM	Urea
500	3	≤3	34
550	4	4	31
600	6	3	41
650	29	15	85
700	35	36	—

^a Uncertainty 10%.

Although the samples with different precursors show small deviations of the N sp³ intensity, it is difficult to find a clear trend for the peaks area ratio, neither in relationship with the precursor nor with the preparation temperature. The fitting results are also affected by a large absolute error, due to the peak superpositions, up to 20% for peak areas. Even without

considering the curve fitting, the simple spectra comparison already gives conflicting results: for instance, in the urea case the better performing (higher temperature) sample shows a lower sp³ degree as compared to the worst performing case; the opposite trend can be found in melamine based samples. By judging the preset data, it is then impossible to directly relate the photocatalytic performances to the sp²/sp³ ratio of the N 1s spectra, as it was proposed in the previous literature.¹⁷

The C 1s spectra for g-C₃N₄ samples are shown on Fig. 6a. Two distinct features are clearly visible in each spectrum: the main BE = 289 eV component correspond to N=C-N bonds, while the lowest BE peak can be described by the sum of cyanide (C=N, BE ≈ 286 eV) and C sp² (C-C, BE ≈ 284.8 eV) contribution. In our case, the vast majority (more than 80%) of the photoemission intensity is ascribed to C-N bond, which is the only one expected in ideal g-C₃N₄. Such result is a further proof of the high quality of these samples and it is consistent with the extremely low variability of the overall N 1s peak shape. The C-C/C=N features, whose intensity slightly changes among the

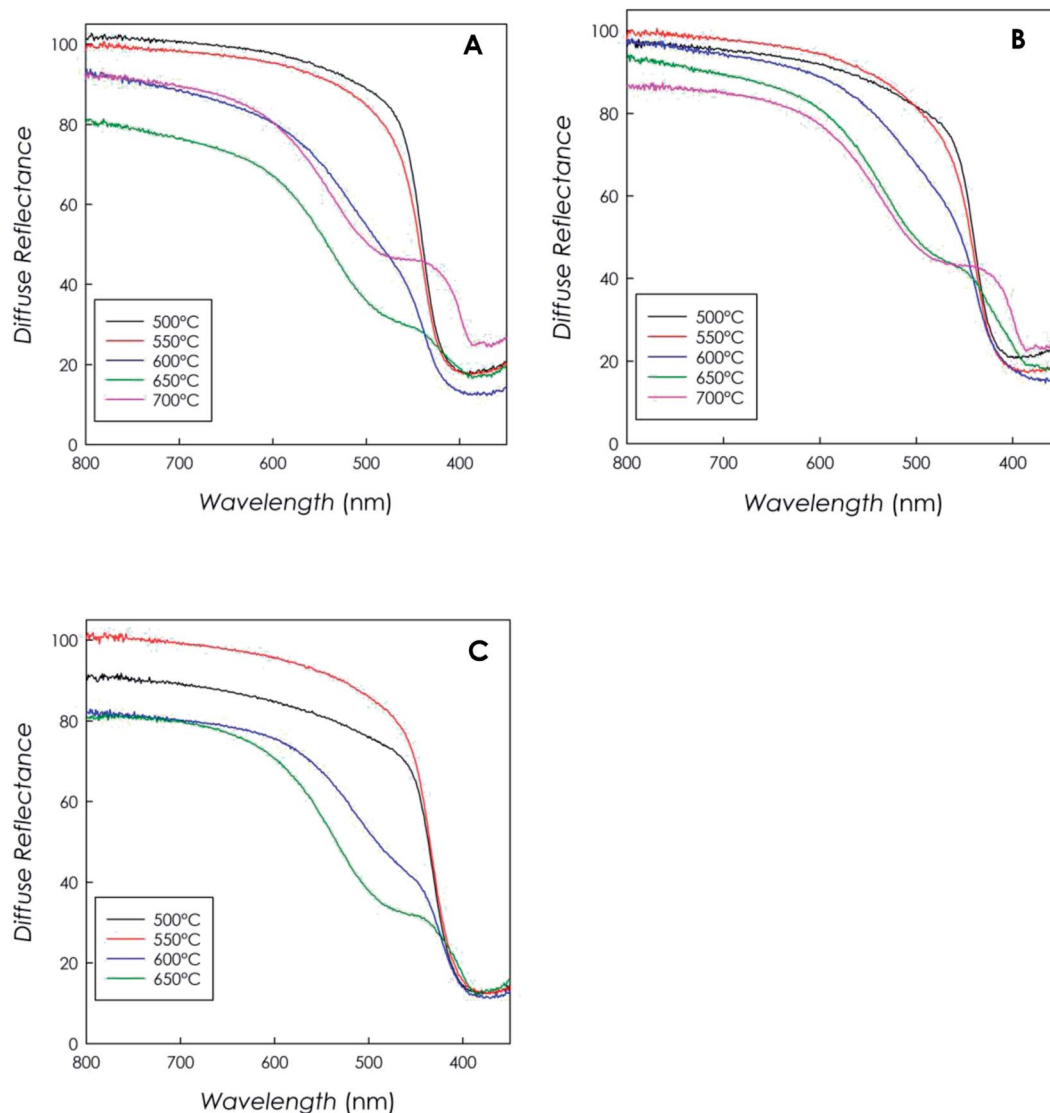


Fig. 4 DRS spectra recorded on the g-C₃N₄ samples obtained from (a) DCD, (b) MLM, (c) urea as function of synthesis temperature.



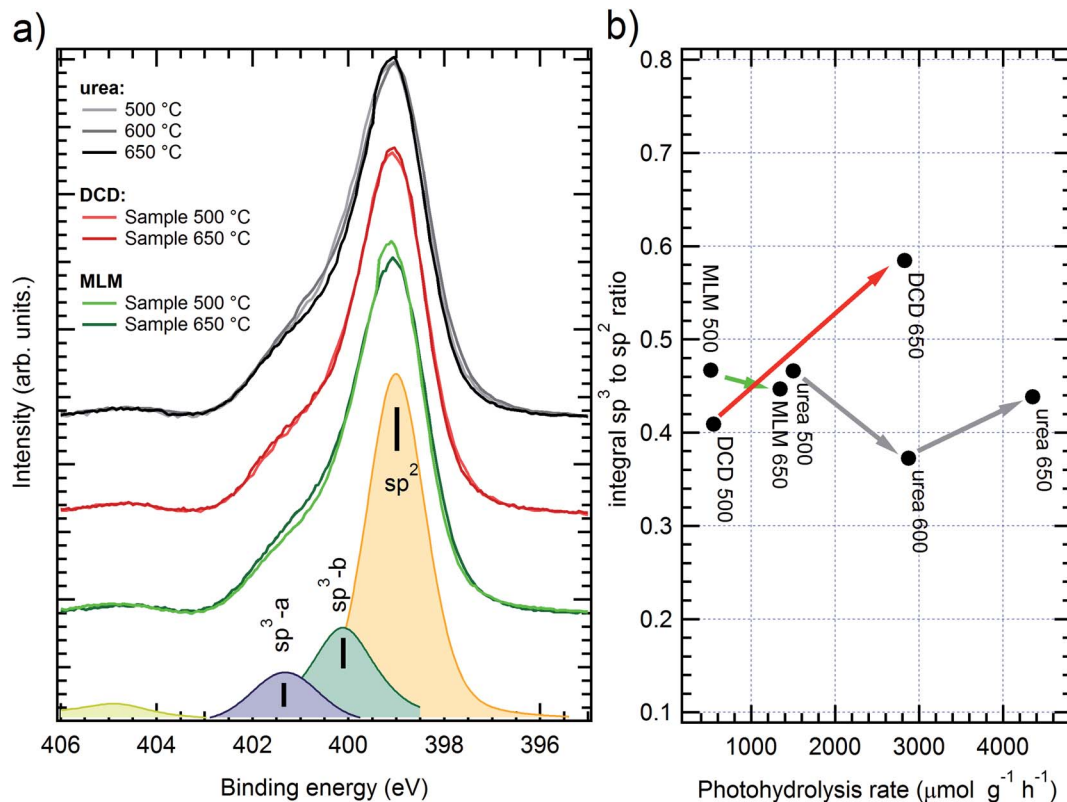


Fig. 5 (a) XPS spectra of N 1s peak on $g\text{-C}_3\text{N}_4$ samples obtained from urea (grey scale colors), DCD (red) and melamine (MLM, green); darker color corresponds to higher polymerization temperature. Peak fitting results for MM sample grown at 500 °C are shown on the bottom. (b) sp^2/sp^3 peaks area ratio dependence on photocatalytic activity; arrows connect samples grown from the same precursor with the raising synthesis temperature.

samples, cannot be ascribed to environmental contamination only, which should appear with a similar amplitude in each case; it should then be ascribed to unpolymersed synthesis by-products. Unlike the case of N 1s sp^2/sp^3 ratio, it is possible to find a direct correlation between the C–C/N=C–N area ratio and the photocatalytic performances. These results, evaluated through Voigt peak fitting, are shown in Fig. 6b. Among each sample precursor class, the H_2 production is systematically higher in samples with a lower C–C peak intensity. In this case, the fit error was much lower (<5% on peak areas) than in the case of the N 1s spectra, further strengthening our results. It should be noted that the intensity of this peak is also inversely related to the macroscopic disorder, since the higher H_2 yields have been measured in the more porous materials; it appears then that the macroscopic disorder alone, due to gaseous product emission during polymerization, does not affect the local molecular ordering (local chemical environment), which improves at higher temperature synthesis. This result is also in agreement with the improved crystallinity of the samples observed by XRD and reported above.

3.6. Photocatalytic H_2 production

The fourteen as-prepared samples have been tested in parallel for H_2 production from aqueous TEOA (10%, v/v) under simulated solar light, in the same conditions (3 wt% Pt, 1 g L^{-1} catalyst, 6 h irradiation). Fig. 7 summarizes the results obtained

in terms of HER ($\mu\text{mol g}^{-1} \text{h}^{-1}$), reported as the mean of three independent irradiation tests.

As it can be seen, H_2 evolution turned out to be dependent on both polymerization temperature and $g\text{-C}_3\text{N}_4$ precursor. In particular, the catalysts produced from DCD provided increasingly enlarged HER as function of temperature up to 650 °C, with a decreased production for the sample obtained at 700 °C (this may be due to a possible detrimental effect of too high surface area³⁵).

The trend was similar for MLM, but in this case the highest production point was observed at the highest synthesis temperature. Urea is the precursor that provided the higher hydrogen production, with a maximum HER of about 4400 $\mu\text{mol g}^{-1} \text{h}^{-1}$ for the sample synthesized at 650 °C (the highest viable temperature for this precursor). This is in accordance with the results recently published by Oh *et al.*,³⁶ who found higher HER from aqueous TEOA using urea rather than MLM and DCD. However, considering the low reaction yield of urea thermal condensation (*ca.* 5%), the semiconductor produced from DCD (reaction yield at 650 °C around 50%) seems most convenient. The control test confirmed that H_2 production is effectively sustained by $g\text{-C}_3\text{N}_4$, indeed H_2 evolution was negligible (0.4 $\mu\text{mol h}^{-1}$) by omitting the catalyst. As well, the key role of Pt co-catalyst in catalyzing water hydrogen ions reduction was confirmed using pure $g\text{-C}_3\text{N}_4$ (from DCD 650 °C), observing a HER of 18 $\mu\text{mol g}^{-1} \text{h}^{-1}$.



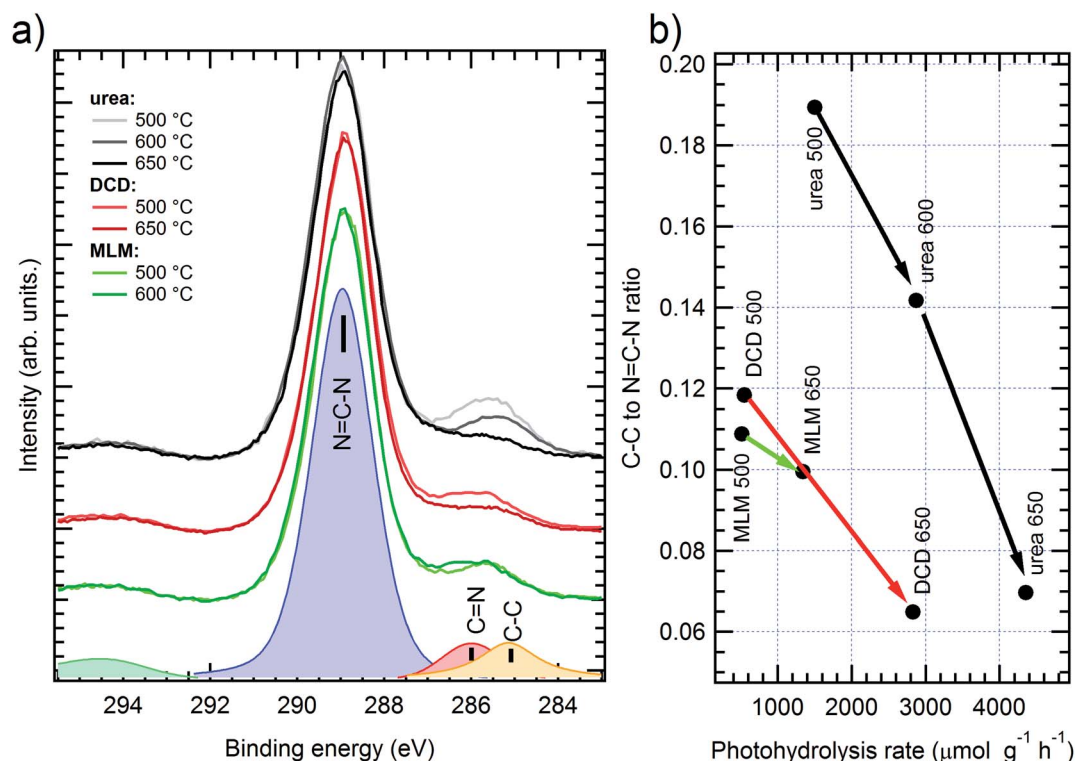


Fig. 6 (a) XPS spectra of C 1s peak of g-C₃N₄ samples, obtained from urea (grey scale colors), DCD (red) and melamine (MLM, green); darker color corresponds to higher polymerization temperature. Peak fitting results for MM sample grown at 650 °C are shown on the bottom. (b) C-C/N=C-N peaks area ratio dependence on photocatalytic activity; arrows connect samples grown with the same precursor with the raising synthesis temperature.

Overall, the best DCD-derived bulk catalyst (650 °C) coupled with Pt provided an apparent quantum yield (AQY)³¹ of 10.7% (the complete list of AQY and turn over number (TON) values are available in ESI†).

The irradiation experiments reproducibility was very good, with values of relative standard deviation (RSD) below 5% ($n = 3$), for all materials. The batch-to-batch reproducibility, evaluated by photoproduction tests on three independently prepared

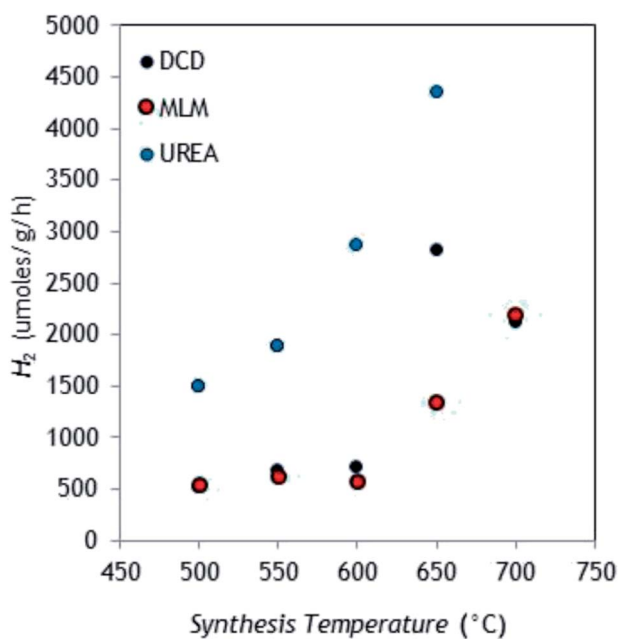


Fig. 7 H₂ evolution profiles obtained under simulated solar light using the g-C₃N₄ samples as function of polymerization temperature and precursor type (RSDs < 5%, $n = 3$).

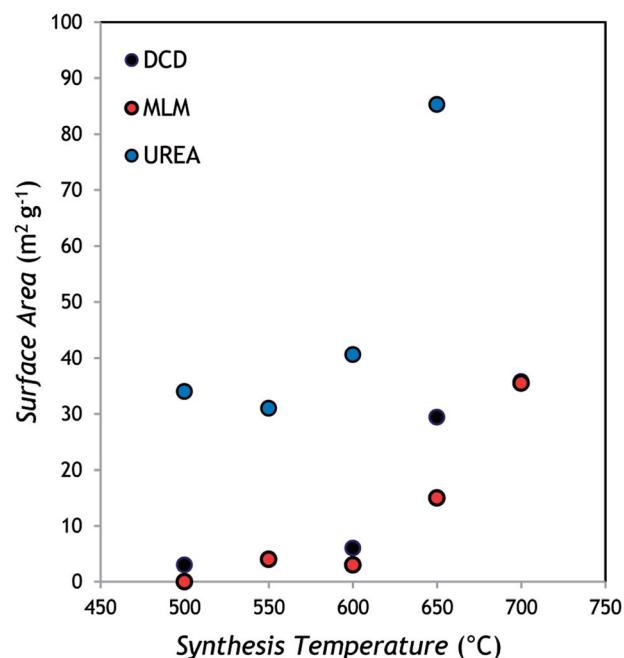


Fig. 8 Correlation between surface area and polymerization temperature for the g-C₃N₄ catalysts.



Table 2 Inter-layer distance, DRS absorption, BET area and HER determined for the set of g-C₃N₄ samples

	Inter-layer spacing (Å)	DRS absorption	BET area (m ² g ⁻¹)	HER (μmol g ⁻¹ h ⁻¹)
DCD	3.23	Almost	29.4	2825
MLM	3.21	superimposable ^a	15	1341
Urea	3.22		85.3	4353

^a See Fig. 4.

batches from DCD (650 °C), provided RSD not higher than 11%, accounting for good overall reproducibility, from g-C₃N₄ synthesis to the final H₂ quantification.

For the interpretation of the H₂ production data, it is useful to follow two distinct approaches. First we have to analyze the HERs within the same samples series (that is from the *same* precursor). The increased photocatalytic activity can be attributed to the combined effects of surface area, visible light harvesting ability, and crystallinity, which are factors that contribute to enlarge g-C₃N₄ HER.^{35,37} As it is shown in the characterization part, these three factors effectively increase along with polymerization temperature, thus reasonably standing for the enhanced photoreaction.

With regard to catalyst porosity, the H₂ evolution profiles showed a superimposable correlation with the catalyst surface area, as it is apparent by comparing Fig. 7 with Fig. 8.

This clearly indicates that the photocatalytic activity of bulk g-C₃N₄ is strictly dependent on the available surface area of the material but also with the trend of the C-C/C-N ratio showed in the XPS results. In fact, the higher is the surface area the higher is the number of available reaction sites for the surface reactions and at the same time lower is recombination of the charge

carriers.^{12,35,39,40} These considerations are further corroborated by comparing the HERs *among* the three precursors (polymerization at 650 °C, for instance), with the corresponding semiconductor physical-chemical properties (Table 2).

From the data gathered in the table, it is clear that, despite the very similar UV-vis absorption (see Fig. 4) and structural properties, HERs are markedly different depending on the g-C₃N₄ precursor, and they are well correlated to surface area. This is in line with the results recently published by Oh *et al.*,³⁶ who suggested that the photocatalytic activity is dominantly affected by surface area rather than light absorption ability. This can be explained not only in terms of available reaction sites,^{39,41} but also considering that the higher is the surface area the more uniform is the size distribution of the co-catalyst.³⁶

Since from the N 1s XPS analysis it has been observed that the trend of sp²/sp³ carbon ratio is unrelated to the H₂ photo-production activity, it seems that the polymerization degree¹⁷ is not the key parameter in determining the overall H₂ evolution activity of bulk g-C₃N₄; however, the C 1s peak analysis suggests that the lower presence of synthesis by-products (obtained with a higher reaction temperature) is positively correlated to a better photocatalysis process.

Table 3 Comparison with recent literature data about H₂ photoproduction using as-prepared and modified g-C₃N₄ catalysts^a

	Precursor	Photoproduction conditions	HER (μmol g ⁻¹ h ⁻¹)	AQY (%)	Ref.
Bulk g-C ₃ N ₄	Urea	1 g L ⁻¹ catalyst, 3 wt% Pt, 10% TEOA, λ < 420 nm	130	n.a.	36
	Urea	1.4 g L ⁻¹ catalyst, 3 wt% Pt, 11% TEOA, UV/Vis	4871 (λ < 400 nm) 1405 (λ > 400 nm)	n.a.	41
	MLM	1 g L ⁻¹ catalyst, 3 wt% Pt, 15% TEOA, λ < 420 nm	80	n.a.	39
	MLM	0.625 g L ⁻¹ catalyst, 1 wt% Au-Pt, 25% methanol, λ > 400 nm	338	n.a.	42
	Urea	1 g L ⁻¹ catalyst, 3 wt% Pt, 10% TEOA, simulated solar light	4353	13.4	This work
	DCD		2825	10.7	
MLM		2196	8.3		
Modified g-C ₃ N ₄	Urea	1 g L ⁻¹ catalyst, 2 wt% Pt, 10% methanol, simulated solar light	2810	17.9 (λ 400 nm)	44
	Urea	0.625 g L ⁻¹ catalyst, 1 wt% Pt, 15% TEOA, λ > 420 nm	213	0.9 (λ 420 nm)	48
	Urea	1 g L ⁻¹ catalyst, 3 wt% Pt, 20% methanol, λ ≥ 420 nm	~420	6.25	43
	MLM	0.5 g L ⁻¹ catalyst, 4 wt% Pt, 10% TEOA, simulated solar light	2040	n.a.	45
	MLM	0.5 g L ⁻¹ catalyst, 1 wt% Pt, 10% TEOA, simulated solar light	8163	n.a.	46
	DCD	0.5 g L ⁻¹ catalyst, 3 wt% Pt, 10% TEOA, simulated solar light	9578	9.01 (λ 420 nm)	47

^a n.a.: not available.



The present investigation showed that thermal condensation is a simple, reproducible way for mass production of structure-controlled bulk g-C₃N₄ semiconductors, which provide good performance for H₂ evolution. As shown in Table 3, gathering some of the most recent applications of g-C₃N₄ (under UV/visible or simulated solar light), HERs and AQYs are competitive with those observed using bulk g-C₃N₄ (ref. 36, 39, 41 and 42) and also with those afforded by modified semiconductors.^{43–48}

4. Conclusions

This paper reported a systematic investigation of bulk g-C₃N₄ prepared from the three most common precursors used, and employing five different reaction temperatures. The investigation of the physico-chemical properties on each sample together with the hydrogen photogeneration activity allowed to clearly extract the key parameters affecting the catalytic activity for H₂ production. In particular, while significant trends in the crystallinity, UV-Vis absorption and XPS data have been observed as a function of the precursor employed and the reaction temperature, it seems that the catalytic properties toward H₂ evolution are dominated by the surface area of the samples. Moreover, we showed, by means of XPS, that the trend of sp²/sp³ carbon ratio is unrelated to the H₂ photoproduction activity, indicating that the polymerization degree is not the key parameter, while the C 1s peak analysis suggests that the lower presence of synthesis by-products is positively correlated to a better photocatalysis process.

Such conclusions, based on a huge analysis of a rich series of samples, provide a conclusive while simple correlation between the photoactivity and electronic, structural and morphological properties of bulk g-C₃N₄ allowing to focus the future research on the enhancement of surface area only. The possible real large-scale application of bulk g-C₃N₄ must take into account not only the catalytic activity but also “practical” aspects such as the polymerization yields and the balance between the amount of photogenerated hydrogen and viability of the synthetic procedure used.

Conflicts of interest

There are no conflicts to declare.

Acknowledgements

This work was partially supported by CATSTER Project within the framework of the Lombardy Region-INSTM Agreement (2015).

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